

BIPOLAR ANALOG INTEGRATED CIRCUIT

μ PC8101GR

150 MHz SILICON QUADRATURE MODULATOR IC FOR DIGITAL MOBILE COMMUNICATIONS

DESCRIPTION

μ PC8101GR is a silicon monolithic integrated circuit designed as up-to-150 MHz quadrature modulator for digital mobile communications, mainly CT2. This modulator consists of digital 90° phase shifter, dual mixers and various buffer amplifiers which are packaged in 20 pin SSOP. Up/down converter IC (μ PC8100GR) is also available as for kit-use with this IC. So, these pair devices contribute to make RF block small, high-performance and low power-consumption.

This product is manufactured using NEC's 20 GHz f_T NESATTMIII silicon bipolar process. This process uses silicon nitride passivation film and gold electrodes. These materials can protect chip surface from external pollution and prevent corrosion and migration. Thus, this product has excellent performance, uniformity and reliability.

FEATURES

- Operating frequency: $f_{IF} = 50 \text{ MHz to } 150 \text{ MHz}$, Local input frequency: $f_{LO} = 100 \text{ MHz to } 300 \text{ MHz}$, $f_{I/Q} = \text{DC to } 500 \text{ kHz}$
- Digital 90° phase shifter is incorporated. (Due to the flip flop phase shifter, $f_{IF} = f_{LO}/2 + f_{I/Q}$.)
- 20 pin SSOP suitable for high-density surface mounting.
- Supply voltage $V_{CC} = 2.7 \text{ to } 5.5 \text{ V}$
- Equipped with Power Save Function.

APPLICATIONS

- Typical application – Digital cordless phone CT2. (In the case of I/Q method)
- Further application – Digital communication equipments.

ORDERING INFORMATION

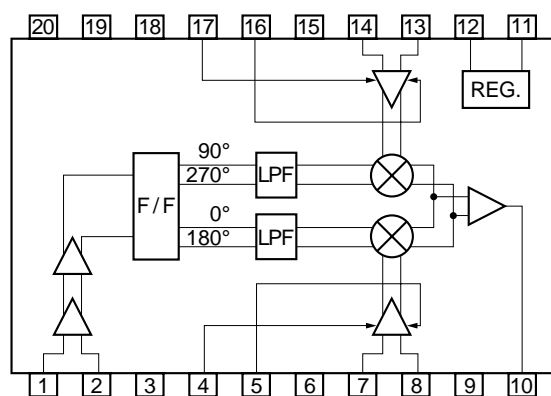
PART NUMBER	PACKAGE	SUPPLYING FORM
μ PC8101GR-E2	20 pin plastic SSOP (225 mil)	Embossed tape 12 mm wide. QTY 2.5 kp/Reel. Pin 1 indicates roll-in direction of tape.

Remark To order evaluation samples, please contact your local NEC sales office. (Order number: μ PC8101GR)

Caution electro-static sensitive devices

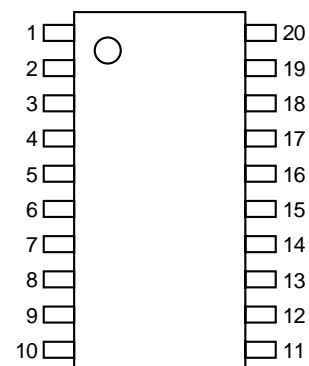
The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.
Not all devices/types available in every country. Please check with local NEC representative for availability and additional information.

INTERNAL BLOCK DIAGRAM AND PIN CONNECTIONS



1. LOCAL IN
2. LOCAL $\overline{\text{IN}}$
3. GND
4. $\overline{\text{Q}}$ - BIAS
5. Q - BIAS
6. GND
7. $\overline{\text{Q}}$ - INPUT
8. Q - INPUT
9. GND
10. IF OUTPUT
11. V_{CC}
12. POWER SAVE
13. I - INPUT
14. $\overline{\text{I}}$ - INPUT
15. GND
16. I - BIAS
17. $\overline{\text{I}}$ - BIAS
18. GND
19. N.C.
20. GND

(Top View)



PIN EXPLANATION

PIN NO.	ASSIGNMENT	APPLIED VOLTAGE (V)	PIN VOLTAGE (V)	FUNCTION AND APPLICATION	EQUIVALENT CIRCUIT
1	LOCAL IN	—	—	Local input for phase shifter. This input impedance is 50 Ω matched internally.	
2	LOCAL $\overline{\text{IN}}$	—	2.0	Bypass of local buffer amplifier input. Grounded through capacitor.	
3	GND	0	—	It must be connected to the system ground with minimum inductance. Ground pattern on the board should be formed as wide as possible. (Track length should be kept as short as possible.)	
4	$\overline{\text{Q}}$ -BIAS	—	0.175	These pins are to adjust local leakage level. These pins should be grounded through register 1 k Ω adjustable 30 mV offset.	
5	Q-BIAS	—	0.175		
6	GND	0	—	Track length should be kept as short as possible.	
7	$\overline{\text{Q}}$ -INPUT	$V_{CC}/2$	—	Input for Q signal. This input impedance is larger than 500 k Ω . As Q signal, $V_{CC}/2$ bias DC signal should be input.	
8	Q-INPUT	$V_{CC}/2$	—	Input for Q signal. This input impedance is larger than 500 k Ω . As Q signal, $V_{CC}/2$ biased 1V _{P-P} signal should be input.	
9	GND	0	—	Track length should be kept as short as possible.	
10	IF OUTPUT	—	1.4	IF output from modulator. This output is emitter follower as 50 Ω impedance. IF output frequency is provided as $f_{IF} = f_{LO}/2 + f_{IQ}$.	
11	V_{CC}	2.7 to 5.5	—	Supply voltage pin.	

PIN NO.	ASSIGNMENT	APPLIED VOLTAGE (V)	PIN VOLTAGE (V)	FUNCTION AND APPLICATION	EQUIVALENT CIRCUIT								
12	POWER SAVE	0 to 5.5	—	Power save control pin. This pin can control ON/OFF operation with bias as follows; <table><tr><td></td><td>Bias: V</td><td>Operation</td></tr><tr><td rowspan="2">V_{PS}</td><td>≥1.8</td><td>ON</td></tr><tr><td>0 to 1.0</td><td>OFF</td></tr></table>		Bias: V	Operation	V _{PS}	≥1.8	ON	0 to 1.0	OFF	
	Bias: V	Operation											
V _{PS}	≥1.8	ON											
	0 to 1.0	OFF											
13	I-INPUT	V _{CC} /2	—	Input for I signal. This input impedance is larger than 500 kΩ. As I signal, V _{CC} /2 biased 1 V _{P-P} MAX. signal should be input.									
14	I-INPUT	V _{CC} /2	—	Input for I signal. This input impedance is larger than 500 kΩ. As I signal, V _{CC} /2 bias DC signal should be input.									
15	GND	0	—	Track length should be kept as short as possible.									
16	I-BIAS	—	0.175	These pins are to adjust local leakage level. These pins should be grounded through register 1 kΩ adjustable 30 mV offset.									
17	I-BIAS	—	0.175										
18	GND	0	—	Track length should be kept as short as possible.									
19	N.C	—	—	Non connection									
20	GND	0	—	Track length should be kept as short as possible.									

* Pin voltage at $V_{CC} = 2.7$ V

ABSOLUTE MAXIMUM RATINGS

Supply Voltage	V_{CC}	$T_A = +25\text{ }^{\circ}\text{C}$	6.0	V
Power Dissipation	P_D	Mounted on $50 \times 50 \times 1.6$ mm double copper clad epoxy glass board at $T_A = +70\text{ }^{\circ}\text{C}$	530	mW
Operating Temperature	T_{opt}		-20 to +70	$^{\circ}\text{C}$
Storage Temperature	T_{stg}		-65 to +150	$^{\circ}\text{C}$

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply Voltage	V_{CC}	2.7	3.0	5.5	V
Operating Temperature	T_{opt}	-20	+25	+70	$^{\circ}\text{C}$

ELECTRICAL CHARACTERISTICS ($T_A = +25\text{ }^{\circ}\text{C}$, UNLESS OTHERWISE SPECIFIED $V_{P/S} \geq 1.8\text{ V}$)

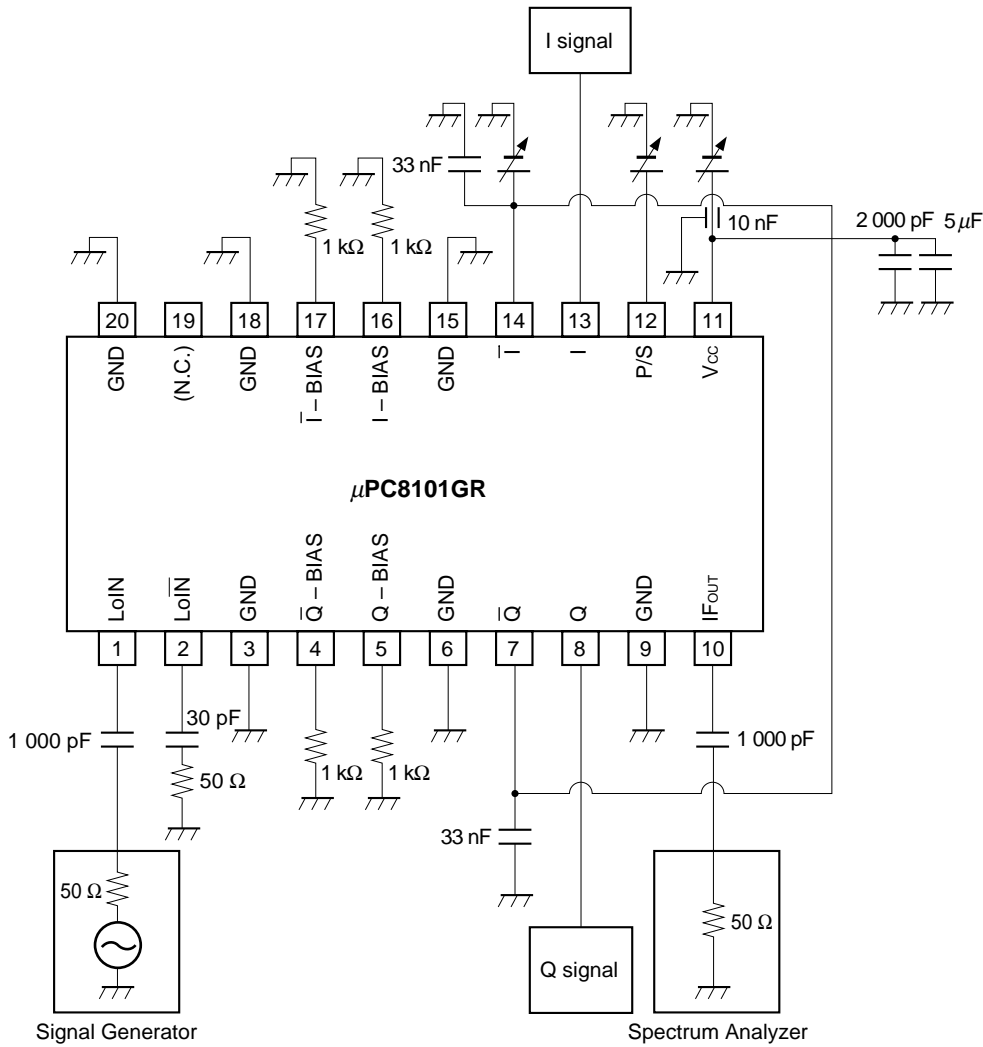
PARAMETER	SYMBOL	$V_{CC} = 2.7\text{ V}$			$V_{CC} = 5.5\text{ V}$			UNIT	TEST CONDITION
		MIN.	TYP.	MAX.	MIN.	TYP.	MAX.		
Circuit current	I_{CC}	10.0	15.0	22.0	17.0	24.5	32.0	mA	No input signal
Circuit current power-save mode	$I_{CC}(P/S)$		330	480		1050	1500	μA	$V_{P/S} \leq 1.0\text{ V}$
IF output level	P_{IFout}	-15	-11	-7.0	-12.5	-7.7	-4.5	dBm	$50\text{ }\Omega$ load, $f = f_{Lo}/2 + f_{I/Q}^{*1}$
Local leakage (carrier)	$ISO(Lo)$	26.0	35.0			30.6		dBc	$f = f_{Lo}/2^{*1}$
Local leak level at IF_{out} pin	Lo_{if}		-49	-37		-39.4	-28	dBm	$I/Q_{input} : DC = V_{CC}/2$
Image rejection (side band leak)	ImR	28.5	37.5		28.5	38.2		dBc	$f = f_{Lo}/2 - f_{I/Q}^{*1}$
I/Q input impedance	$Z_{I/Q}$	500	1 000		500	700		k Ω	$I/Q_{bias} = 2.75\text{ V}$
Power-save response time	rise time	$T_{P/S}(RISE)$	1.0	5.0		1.0	5.0	μs	$V_{P/S}(OFF) \rightarrow V_{P/S}(ON)$
	fall time	$T_{P/S}(FALL)$	1.0	3.0		1.0	3.0	μs	$V_{P/S}(ON) \rightarrow V_{P/S}(OFF)$
Power-save control voltage	$V_{P/S}(ON)$	1.8		5.5	1.8		5.5	V	Normal operation
	$V_{P/S}(OFF)$			1.0			1.0	V	Power-save mode
Local input level	$P_{Lo_{in}}$	-17		-7	-17		-7	dBm	

STANDARD CHARACTERISTICS FOR REFERENCE**($T_A = +25\text{ }^{\circ}\text{C}$, UNLESS OTHERWISE SPECIFIED $V_{P/S} \geq 1.8\text{ V}$)**

PARAMETER	SYMBOL	$V_{CC} = 2.7\text{ V}$			$V_{CC} = 5.5\text{ V}$			UNIT	TEST CONDITION
		MIN.	TYP.	MAX.	MIN.	TYP.	MAX.		
3rd order distortion of I/Q	$IM_{3I/Q}$		-37.3			-56.5		dBc	$f = f_{Lo}/2 - 3f_{I/Q}^{*1}$
Local input VSWR	$VSWR_{Lo_{in}}$		1.1			1.1		X : 1	
IF output VSWR	$VSWR_{IFout}$		1.2			1.2		X : 1	

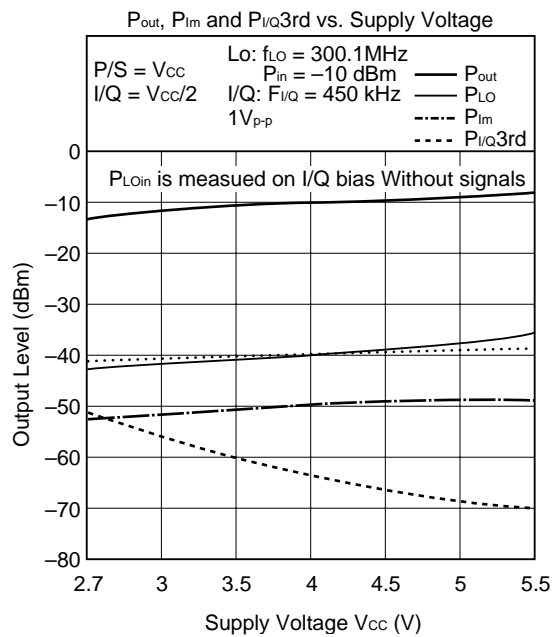
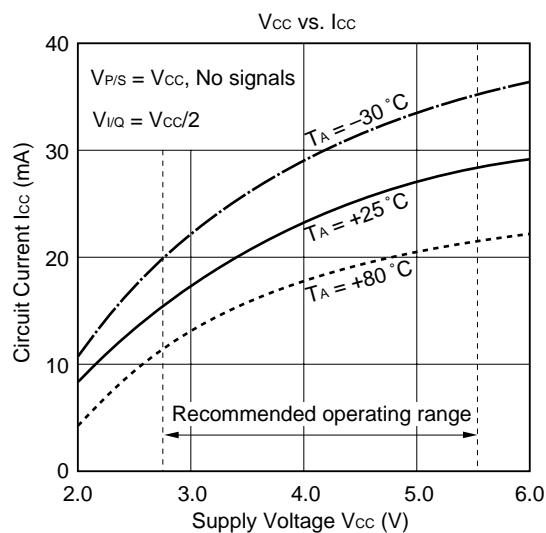
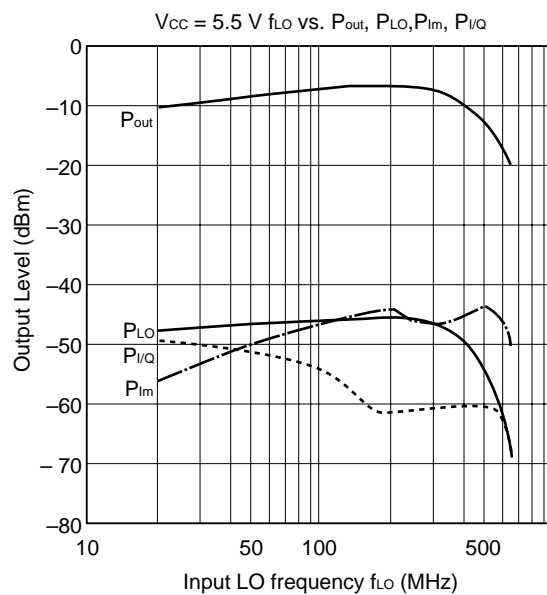
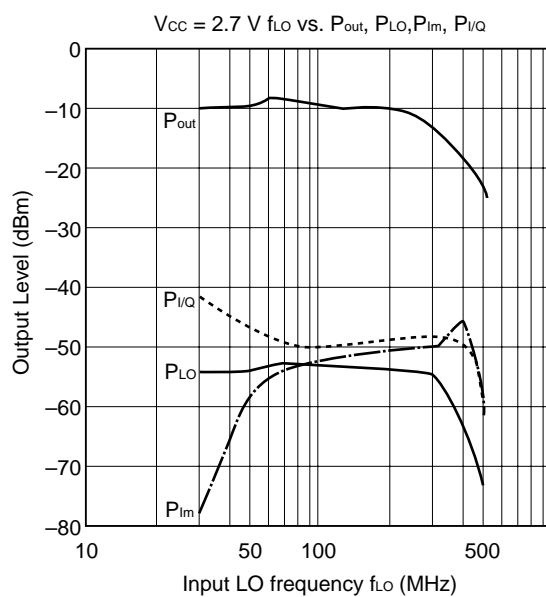
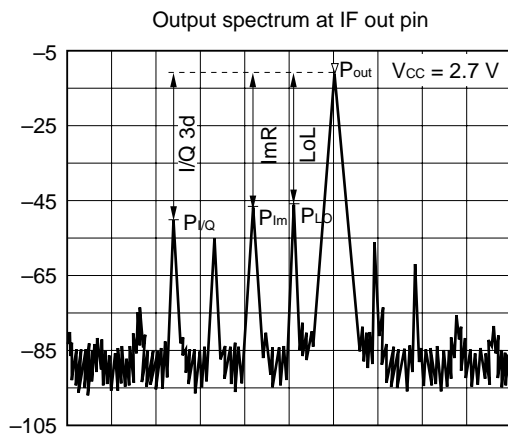
*1 : $f_{Lo_{in}} = 300.1\text{ MHz}$ $P_{Lo_{in}} = -10\text{ dBm}$
 $f_{I/Q} = 36\text{ kHz}$ $1\text{ V}_{P-P}\text{ DC} = V_{CC}/2$

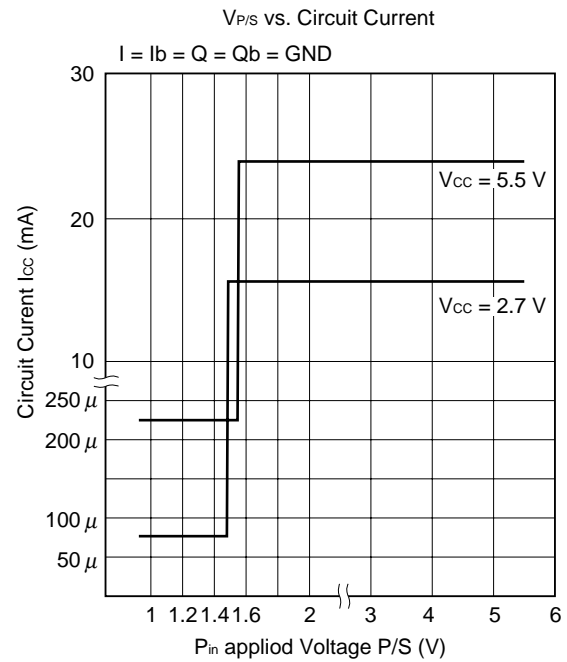
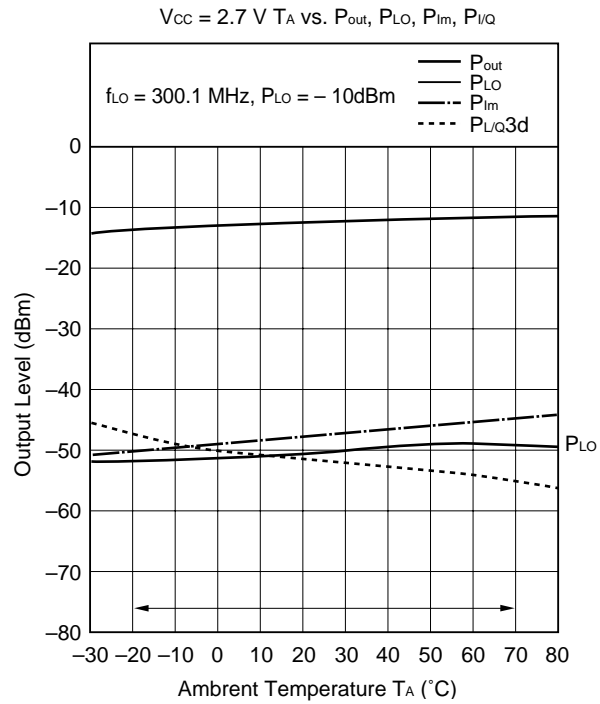
TEST CIRCUIT



SIGNAL	f _(MHz)	P _{IN}	
Lo	300.1 MHz	-10 dBm	
I signal	36 kHz	1 V _{P-P}	I/Q phase difference = 90° In the case of local leak level measurement, I/Q signal is applied as only DC.
Q signal	36 kHz	1 V _{P-P}	

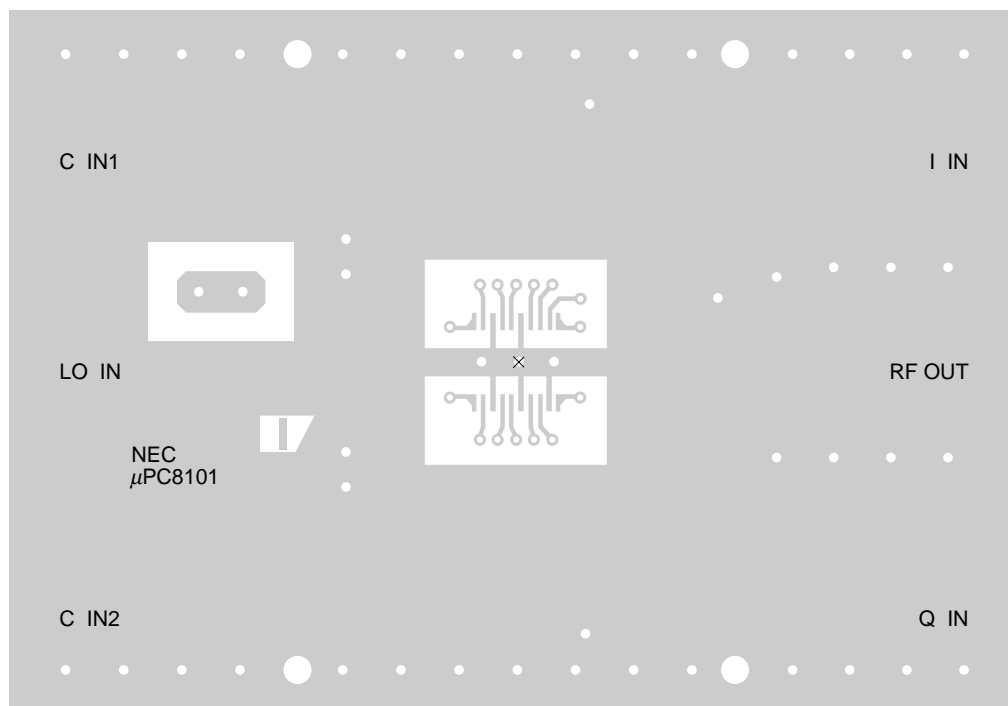
SYMBOL	Applied voltage (V)
V _{CC} = V _{P/S}	2.7 to 5.5 V
V _I = V _{Ib} = V _O = V _{Ob}	0.5 × V _{CC}

TYPICAL CHARACTERISTICS (Unless otherwise specified $T_A = +25^\circ\text{C}$)

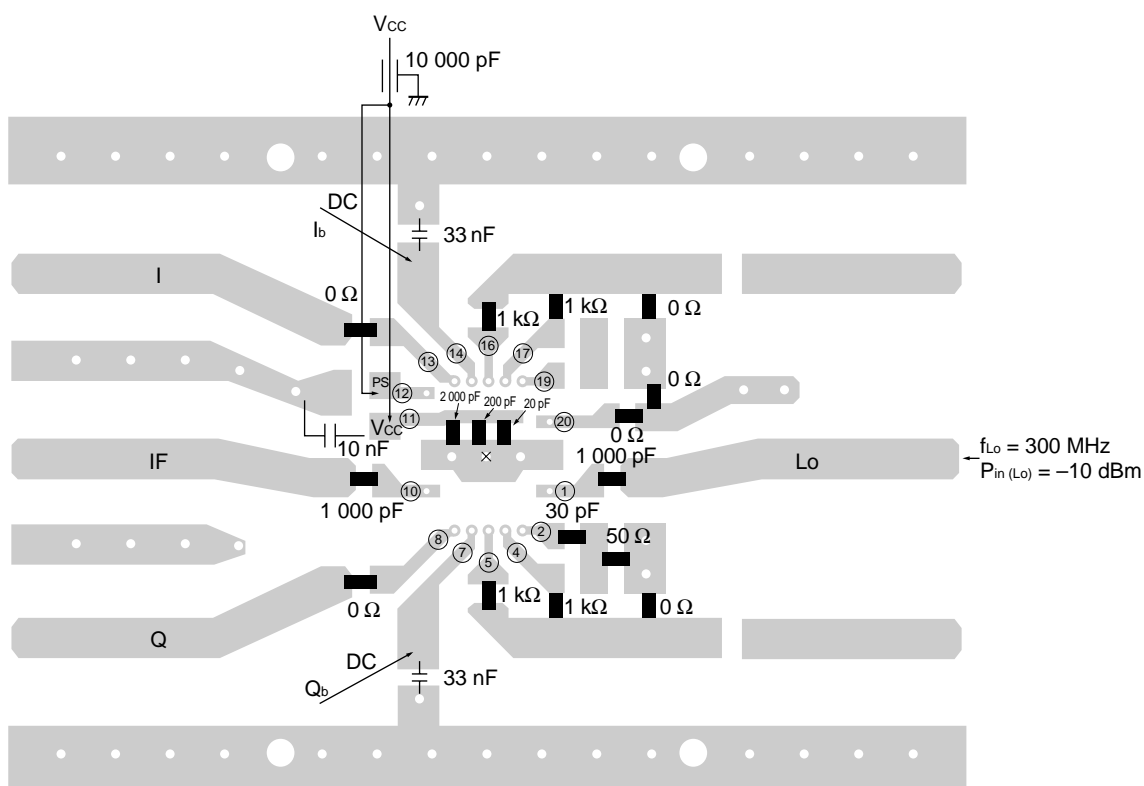


TEST CIRCUIT ASSEMBLED ON EVALUATION BOARD

IC MOUNTED SIDE

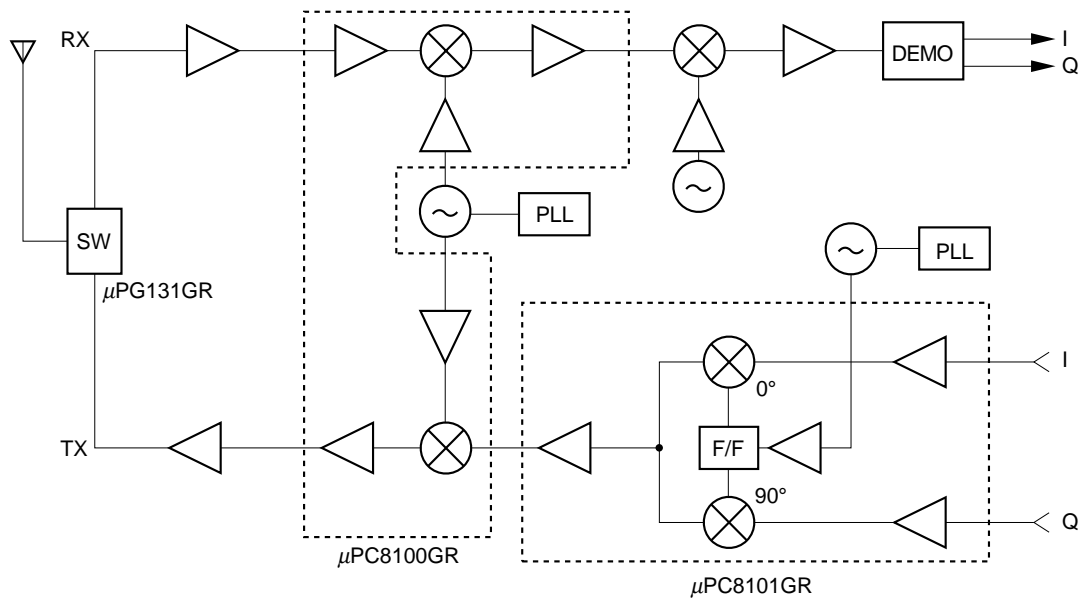


COMPONENT MOUNTED SIDE



TYPICAL APPLICATION

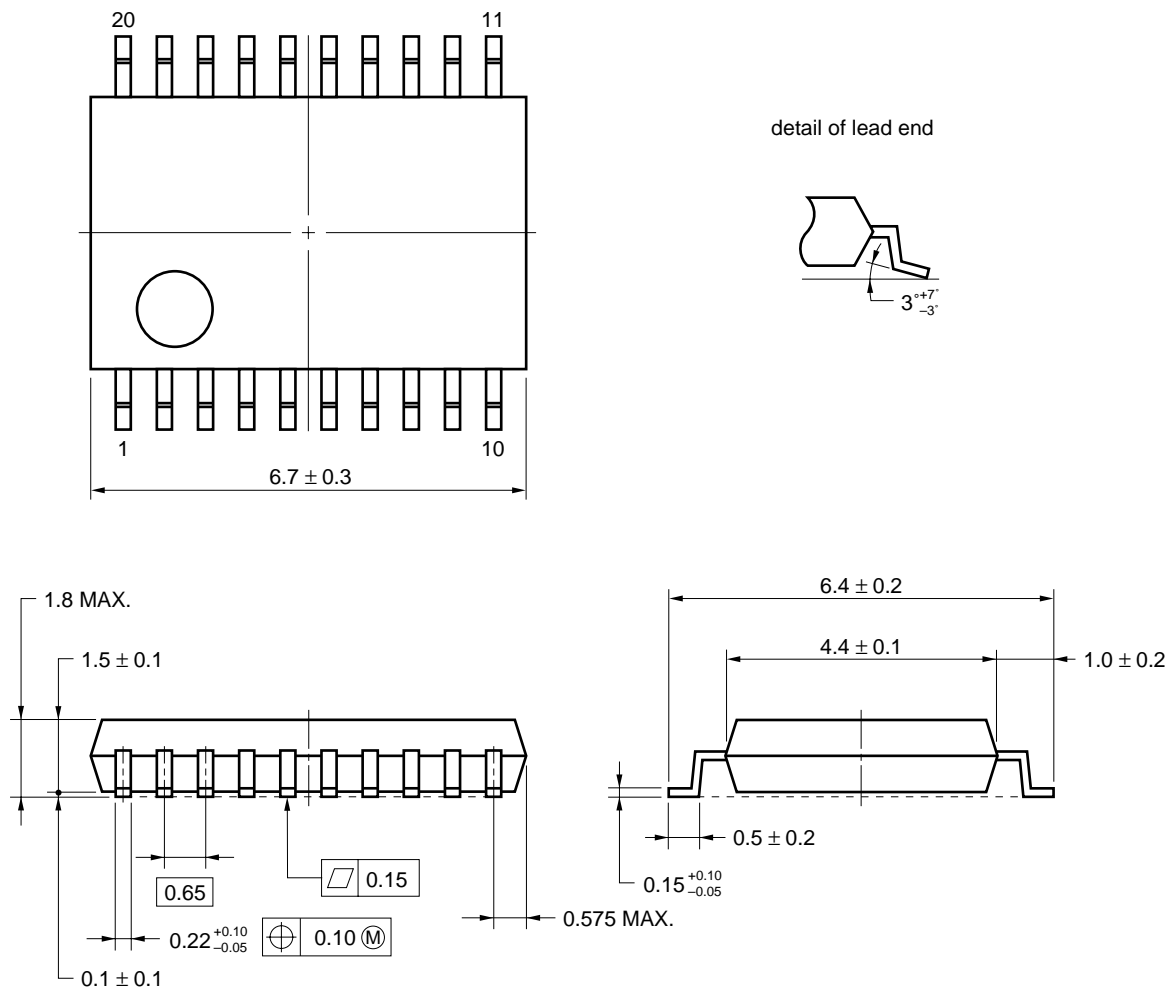
CT2 BLOCK DIAGRAM



The application circuits and their parameters are for references only and are not intended for use in actual design-in's.

PACKAGE DIMENSIONS

★ 20 PIN PLASTIC SSOP (225 mil) (UNIT: mm)



NOTE Each lead centerline is located within 0.10 mm of its true position (T.P.) at maximum material condition.

NOTE ON CORRECT USE

- (1) Observe precautions for handling because of electrostatic sensitive devices.
- (2) Form a ground pattern as wide as possible to minimize ground impedance (to prevent undesired operation).
- (3) Keep the track length of the ground pins as short as possible.
- (4) Connect a bypass capacitor (e.g. 1 000 pF) to the Vcc pin.

RECOMMENDED SOLDERING CONDITIONS

This product should be soldered in the following recommended conditions. Other soldering method and conditions than the recommended conditions are to be consulted with our sales representatives.

μPC8101GR

Soldering process	Soldering conditions	Symbol
Infrared ray reflow	Peak package's surface temperature: 235 °C or below, Reflow time: 30 seconds or below (210 °C or higher), Number of reflow process: 2, Exposure limit*: None	IR35-00-2
VPS	Peak package's surface temperature: 215 °C or below, Reflow time: 40 seconds or below (200 °C or higher), Number of reflow process: 2, Exposure limit*: None	VP15-00-2
Wave soldering	Solder temperature: 260 °C or below, Flow time: 10 seconds or below Number of flow process: 1, Exposure limit*: None	WS60-00-1
Partial heating method	Terminal temperature: 300 °C or below, Flow time: 10 seconds or below, Exposure limit*: None	

*: Exposure limit before soldering after dry-pack package is opened.

Storage conditions: 25 °C and relative humidity at 65 % or less.

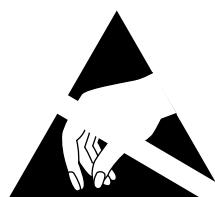
Note: Apply only a single process at once, except for "Partial heating method".

For details of recommended soldering conditions for surface mounting, refer to information document SEMICONDUCTOR DEVICE MOUNTING TECHNOLOGY MANUAL (C10535E).

[MEMO]

[MEMO]

[MEMO]



ATTENTION

OBSERVE PRECAUTIONS
FOR HANDLING
ELECTROSTATIC
SENSITIVE
DEVICES

NESAT (NEC Silicon Advanced Technology) is a trademark of NEC Corporation.

- **The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.**
 - No part of this document may be copied or reproduced in any form or by any means without the prior written consent of NEC Corporation. NEC Corporation assumes no responsibility for any errors which may appear in this document.
 - NEC Corporation does not assume any liability for infringement of patents, copyrights or other intellectual property rights of third parties by or arising from use of a device described herein or any other liability arising from use of such device. No license, either express, implied or otherwise, is granted under any patents, copyrights or other intellectual property rights of NEC Corporation or others.
 - Descriptions of circuits, software, and other related information in this document are provided for illustrative purposes in semiconductor product operation and application examples. The incorporation of these circuits, software, and information in the design of the customer's equipment shall be done under the full responsibility of the customer. NEC Corporation assumes no responsibility for any losses incurred by the customer or third parties arising from the use of these circuits, software, and information.
 - While NEC Corporation has been making continuous effort to enhance the reliability of its semiconductor devices, the possibility of defects cannot be eliminated entirely. To minimize risks of damage or injury to persons or property arising from a defect in an NEC semiconductor device, customers must incorporate sufficient safety measures in its design, such as redundancy, fire-containment, and anti-failure features.
 - NEC devices are classified into the following three quality grades:
 "Standard", "Special", and "Specific". The Specific quality grade applies only to devices developed based on a customer designated "quality assurance program" for a specific application. The recommended applications of a device depend on its quality grade, as indicated below. Customers must check the quality grade of each device before using it in a particular application.
 - Standard: Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots
 - Special: Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)
 - Specific: Aircraft, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems or medical equipment for life support, etc.
- The quality grade of NEC devices is "Standard" unless otherwise specified in NEC's Data Sheets or Data Books. If customers intend to use NEC devices for applications other than those specified for Standard quality grade, they should contact an NEC sales representative in advance.